

FEATURES

- Offset voltage: 400 μV typical
- Low offset voltage drift: 6 $\mu\text{V}/^\circ\text{C}$ maximum (AD8692/AD8694)
- Very low input bias currents: 1 pA maximum
- Low noise: 8 nV/ $\sqrt{\text{Hz}}$
- Low distortion: 0.0006%
- Wide bandwidth: 10 MHz
- Unity-gain stable
- Single-supply operation: 2.7 V to 6 V
- Qualified for automotive applications

APPLICATIONS

- Photodiode amplification
- Battery-powered instrumentation
- Medical instruments
- Multipole filters
- Sensors
- Portable audio devices

GENERAL DESCRIPTION

The AD8691, AD8692, and AD8694 are low cost, single, dual, and quad rail-to-rail output, single-supply amplifiers featuring low offset and input voltages, low current noise, and wide signal bandwidth. The combination of low offset, low noise, very low input bias currents, and high speed make these amplifiers useful in a wide variety of applications. Filters, integrators, photodiode amplifiers, and high impedance sensors all benefit from this combination of performance features. Audio and other ac applications benefit from the wide bandwidth and low distortion of these devices.

Applications for these amplifiers include power amplifier (PA) controls, laser diode control loops, portable and loop-powered instrumentation, audio amplification for portable devices, and ASIC input and output amplifiers.

The small SC70 and TSOT package options for the AD8691 allow it to be placed next to sensors, thereby reducing external noise pickup.

The AD8691, AD8692, and AD8694 are specified over the extended industrial temperature range of -40°C to $+125^\circ\text{C}$. The AD8691 single is available in 5-lead SC70 and 5-lead TSOT packages. The AD8692 dual is available in 8-lead MSOP and narrow SOIC surface-mount packages. The AD8694 quad is available in 14-lead TSSOP and narrow 14-lead SOIC packages.

See the Ordering Guide section for automotive grades.

PIN CONFIGURATIONS

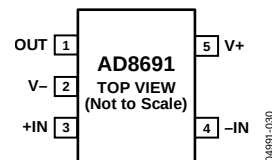


Figure 1. 5-Lead TSOT

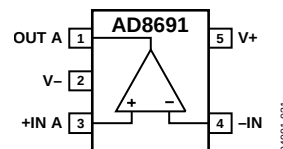


Figure 2. 5-Lead SC70

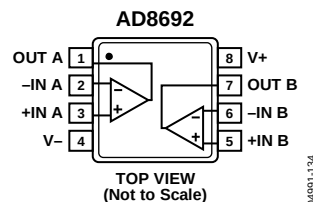


Figure 3. 8-Lead SOIC and 8-Lead MSOP

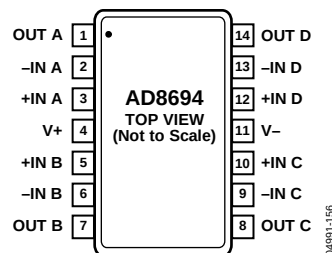


Figure 4. 14-Lead SOIC and 14-Lead TSSOP

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9/13—Rev. E to Rev. F

Changes to Figure 3 and Figure 4	1
Delete Figure 4 and Figure 5; Renumbered Sequentially	1
Changes to Ordering Guide	14

8/11—Rev. D to Rev. E

Changes to Figure 20	8
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11/10—Rev. C to Rev. D

Changes to Features Section and General Descriptions Section	1
Updated Outline Dimensions	11
Changes to Ordering Guide	14
Added Automotive Products Section	14

5/07—Rev. B to Rev. C

Change to Figure 1	1
Changes to Large Signal Voltage Gain Values in Table 1	3
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3/05—Rev. A to Rev. B

Added AD8694	Universal
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1/05—Rev. 0 to Rev. A

Added AD8691	Universal
Changes to Features	1
Added Figure 1 and Figure 2	1
Changes to Electrical Characteristics	3
Changes to Figure 6 caption	6
Changes to Figure 9	6
Updated Outline Dimensions	11
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10/04—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS

$V_S = 2.7\text{ V}$, $V_{CM} = V_S/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V _{OS}	V _{CM} = −0.3 V to +1.6 V V _{CM} = −0.1 V to +1.6 V; −40°C < T _A < +125°C		0.4	2.0	mV
Input Bias Current	I _B				3.0	mV
		−40°C < T _A < +85°C		0.2	1	pA
Input Offset Current	I _{OS}	−40°C < T _A < +125°C			50	pA
					260	pA
		−40°C < T _A < +85°C	0.1	0.5	pA	
		−40°C < T _A < +125°C			20	pA
					75	pA
Input Voltage Range			−0.3		+1.6	V
Common-Mode Rejection Ratio	CMRR	V _{CM} = −0.3 V to +1.6 V	68	90		dB
		V _{CM} = −0.1 V to +1.6 V; −40°C < T _A < +125°C	60	85		dB
Large Signal Voltage Gain	A _{VO}					
AD8691/AD8692		R _L = 2 kΩ, V _O = 0.5 V to 2.2 V	90	250		V/mV
AD8694		R _L = 2 kΩ, V _O = 0.5 V to 2.2 V	60			V/mV
Offset Voltage Drift	ΔV _{OS} /ΔT					
AD8691				2	12	μV/°C
AD8692/AD8694				1.3	6	μV/°C
INPUT CAPACITANCE						
Common-Mode Input Capacitance	C _{CM}			5		pF
Differential Input Capacitance	C _{DM}			2.5		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	V _{OH}	I _L = 1 mA −40°C < T _A < +125°C	2.64	2.66		V
Output Voltage Low	V _{OL}	I _L = 1 mA		25	40	V
		−40°C < T _A < +125°C			60	mV
Short-Circuit Current	I _{SC}			±20		mV
Closed-Loop Output Impedance	Z _{OUT}	f = 1 MHz, A _V = 1		12		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	V _S = 2.7 V to 5.5 V −40°C < T _A < +125°C	80	95		Ω
Supply Current/Amplifier	I _{SY}	V _O = 0 V	75	95		V
		−40°C < T _A < +125°C		0.85	0.95	mV
					1.2	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	R _L = 2 kΩ		5		mV
Settling Time	t _S	To 0.01%		1		μs
Gain Bandwidth Product	GBP			10		μs
Phase Margin	Ø _m			60		MHz
Total Harmonic Distortion + Noise	THD + N	G = 1, R _L = 600 Ω, f = 1 kHz, V _O = 250 mV p-p		0.003		Degrees
NOISE PERFORMANCE						
Voltage Noise	e _n p-p	f = 0.1 Hz to 10 Hz		1.6	3.0	%
Voltage Noise Density	e _n	f = 1 kHz		8	12	
		f = 10 kHz		6.5		nV p-p
Current Noise Density	i _n	f = 1 kHz		0.05		nV/√Hz
						pA/√Hz

$V_S = 5.0\text{ V}$, $V_{CM} = V_S/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$V_{CM} = -0.3\text{ V to }+3.9\text{ V}$ $V_{CM} = -0.1\text{ V to }+3.9\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.4	2.0	mV
Input Bias Current	I_B			0.2	1	pA
		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			50	pA
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			260	pA
Input Offset Current	I_{OS}			0.1	0.5	pA
		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			20	pA
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			75	pA
Input Voltage Range			-0.3		+3.9	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.3\text{ V to }+3.9\text{ V}$ $V_{CM} = -0.1\text{ V to }+3.9\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$	70	95		dB
			67	95		dB
Large Signal Voltage Gain	A_{VO}	$V_O = 0.5\text{ V to }4.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_{CM} = 0\text{ V}$ $V_O = 0.5\text{ V to }4.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_{CM} = 0\text{ V}$	250	2000		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$					V/mV
				2	12	$\mu\text{V}/^\circ\text{C}$
				1.3	6	$\mu\text{V}/^\circ\text{C}$
INPUT CAPACITANCE						
Common-Mode Input Capacitance	C_{CM}			5		pF
Differential Input Capacitance	C_{DM}			2.5		pF
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	$I_L = 1\text{ mA}$ $I_L = 10\text{ mA}$ $-40^\circ\text{C to }+125^\circ\text{C}$	4.96 4.7 4.6	4.98 4.78		V V V
Output Voltage Low	V_{OL}	$I_L = 1\text{ mA}$ $I_L = 10\text{ mA}$ $I_L = 10\text{ mA}$ $-40^\circ\text{C to }+125^\circ\text{C}$ $-40^\circ\text{C to }+125^\circ\text{C}$		20 165 185	40 210 240	mV mV mV
					290	mV
					370	mV
Short-Circuit Current	I_{SC}			± 80		mA
Closed-Loop Output Impedance	Z_{OUT}	$f = 1\text{ MHz}$, $A_v = 1$		10		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = 2.7\text{ V to }5.5\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	80 75	95 95		dB dB
Supply Current/Amplifier	I_{SY}	$V_O = 0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.95	1.05	mA
					1.3	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		5		V/ μs
Settling Time	t_s	To 0.01%		1		μs
Full Power Bandwidth	BW_P	<1% distortion		360		kHz
Gain Bandwidth Product	GBP			10		MHz
Phase Margin	ϕ_m			65		Degrees
Total Harmonic Distortion + Noise	THD + N	$G = 1$, $R_L = 600\text{ }\Omega$, $f = 1\text{ kHz}$, $V_O = 1\text{ V p-p}$		0.0006		%
NOISE PERFORMANCE						
Voltage Noise	$e_{n\text{ p-p}}$	$f = 0.1\text{ Hz to }10\text{ Hz}$		1.6	3.0	$\mu\text{V p-p}$
Voltage Noise Density	e_n	$f = 1\text{ kHz}$		8	12	nV/ $\sqrt{\text{Hz}}$
	e_n	$f = 10\text{ kHz}$		6.5		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	i_n	$f = 1\text{ kHz}$		0.05		pA/ $\sqrt{\text{Hz}}$

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

Parameter	Rating
Supply Voltage	6 V
Input Voltage	$V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$
Differential Input Voltage	$\pm 6\text{ V}$
Output Short-Circuit Duration to GND	Observe derating curves
Storage Temperature Range	-65°C to $+150^\circ\text{C}$
Operating Temperature Range	-40°C to $+125^\circ\text{C}$
Junction Temperature Range	-65°C to $+150^\circ\text{C}$
Lead Temperature (Soldering, 60 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

θ_{JA} is specified for the worst-case conditions, that is, the device soldered in the circuit board for surface-mount packages.

Table 4. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
8-Lead MSOP (RM-8)	210	45	$^\circ\text{C}/\text{W}$
8-Lead SOIC (R-8)	158	43	$^\circ\text{C}/\text{W}$
5-Lead TSOT (UJ-5)	207	61	$^\circ\text{C}/\text{W}$
5-Lead SC70 (KS-5)	376	126	$^\circ\text{C}/\text{W}$
14-Lead TSSOP (RU-14)	180	35	$^\circ\text{C}/\text{W}$
14-Lead SOIC (R-14)	120	36	$^\circ\text{C}/\text{W}$

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

$V_S = +5\text{ V}$ or $\pm 2.5\text{ V}$, unless otherwise noted.

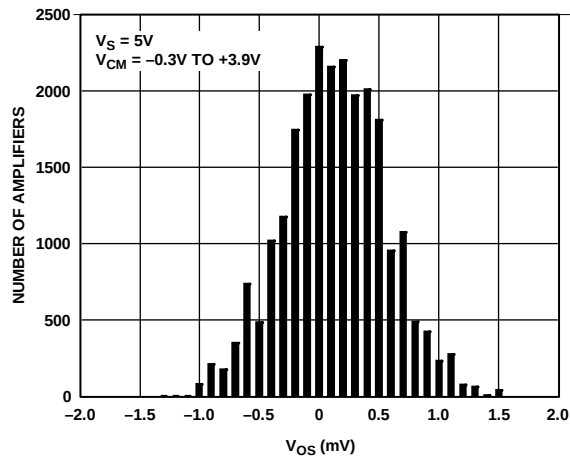


Figure 5. Input Offset Voltage Distribution

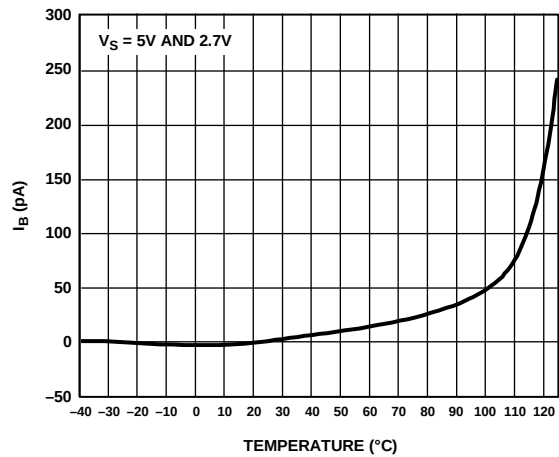


Figure 8. Input Bias Current vs. Temperature

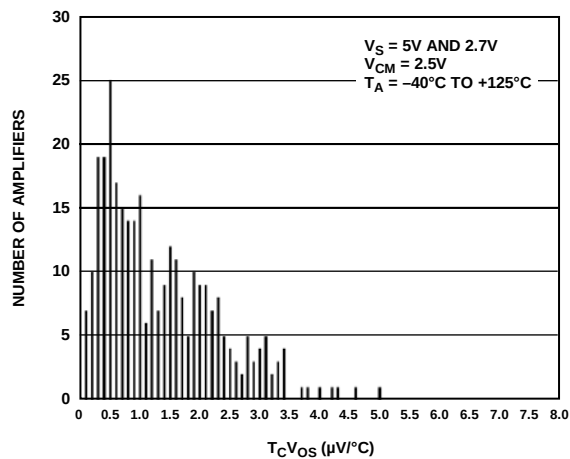


Figure 6. AD8692/AD8694 Input Offset Voltage Drift Distribution

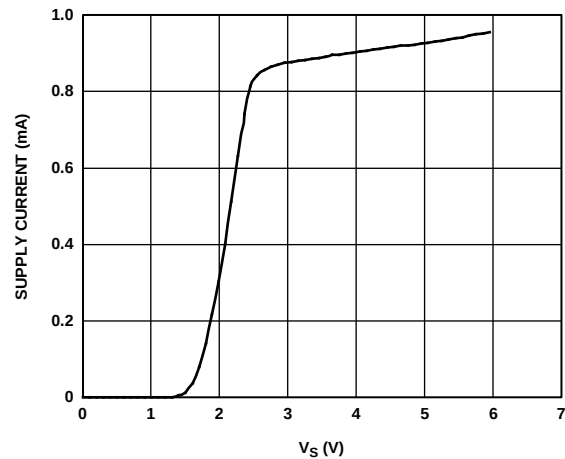


Figure 9. Supply Current vs. Supply Voltage

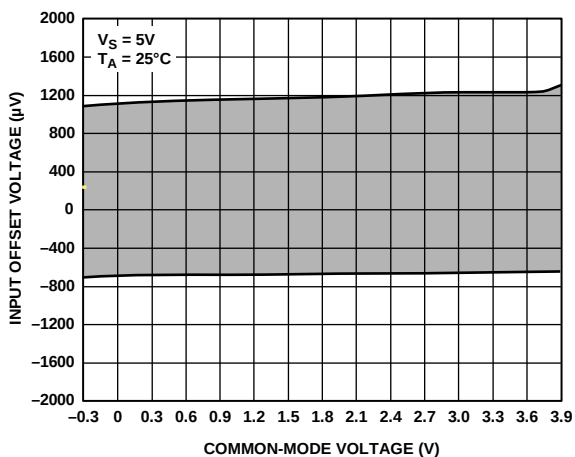


Figure 7. Input Offset Voltage vs. Common-Mode Voltage

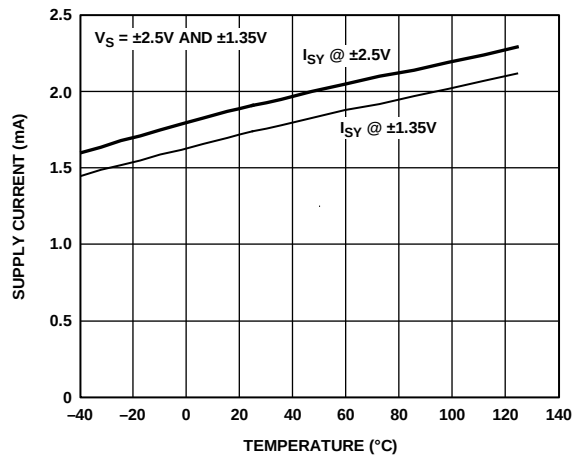


Figure 10. Supply Current vs. Temperature

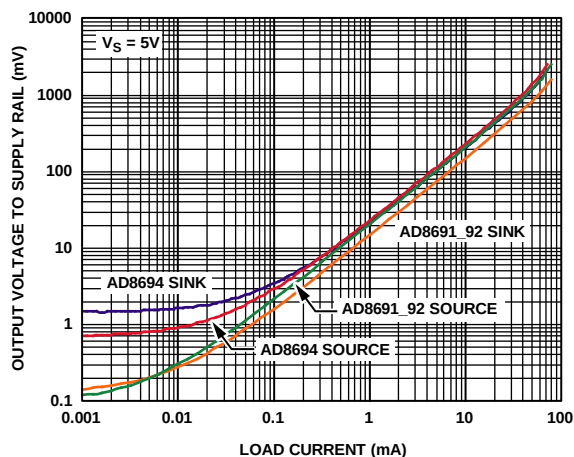


Figure 11. Output Voltage to Supply Rail vs. Load Current

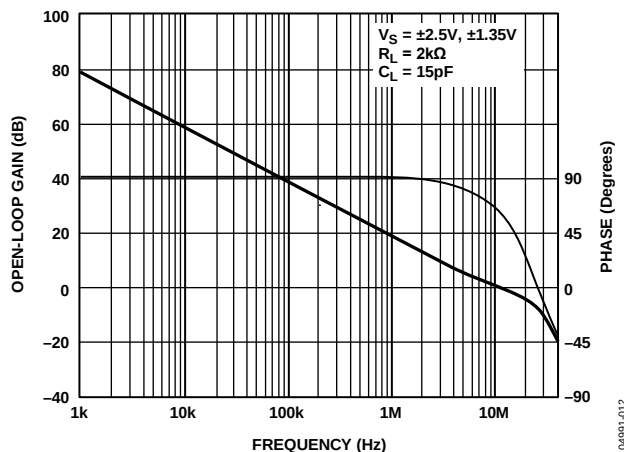


Figure 14. Open-Loop Gain and Phase vs. Frequency

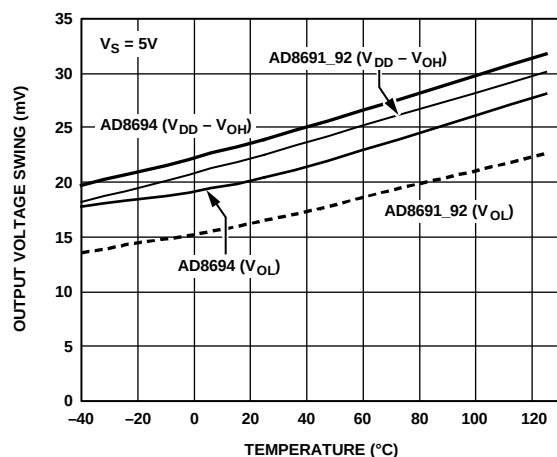
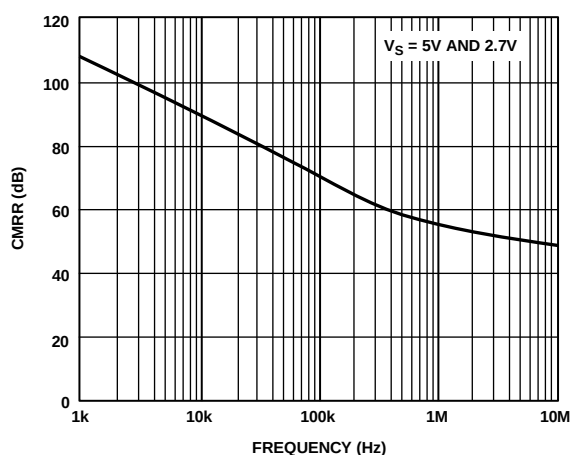
Figure 12. Output Voltage Swing vs. Temperature ($I_L = 1$ mA)

Figure 15. CMRR vs. Frequency

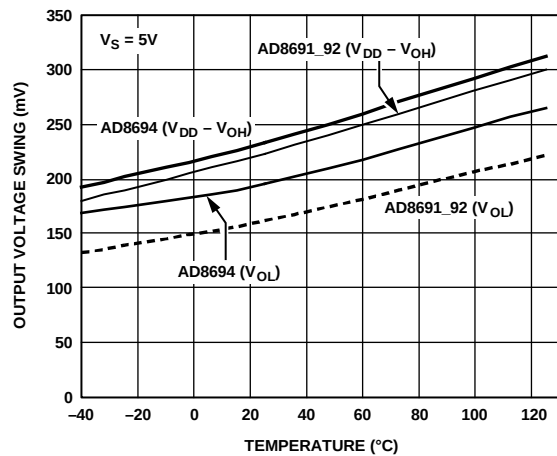
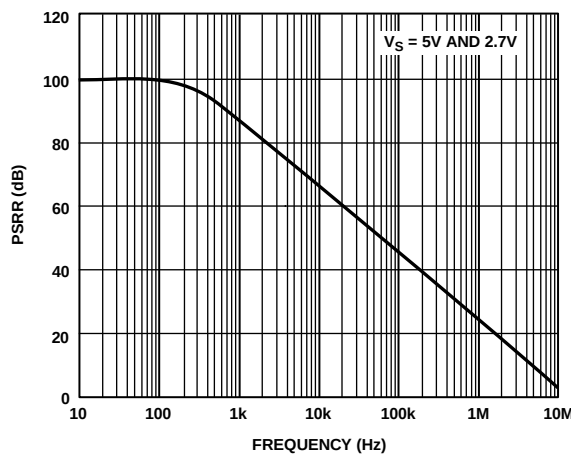
Figure 13. Output Voltage Swing vs. Temperature ($I_L = 10$ mA)

Figure 16. PSRR vs. Frequency

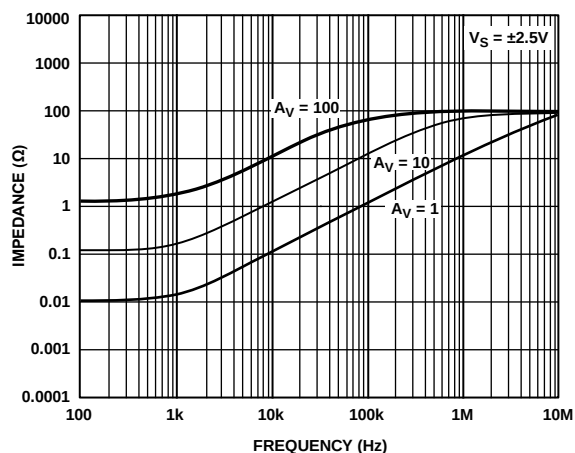


Figure 17. Closed-Loop Output Impedance vs. Frequency

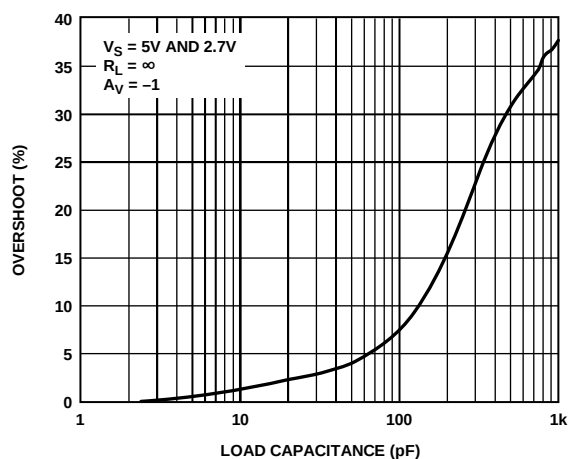


Figure 18. Small Signal Overshoot vs. Load Capacitance

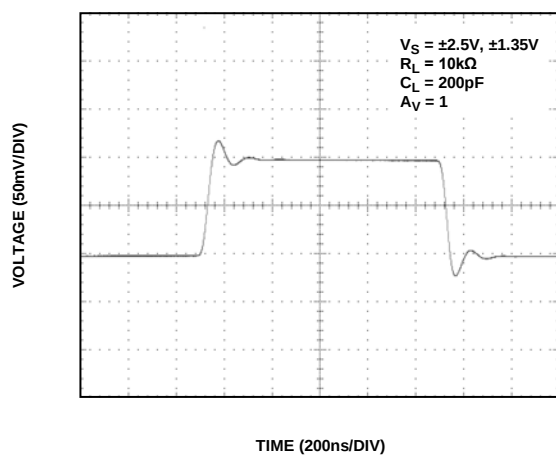


Figure 19. Small Signal Transient Response

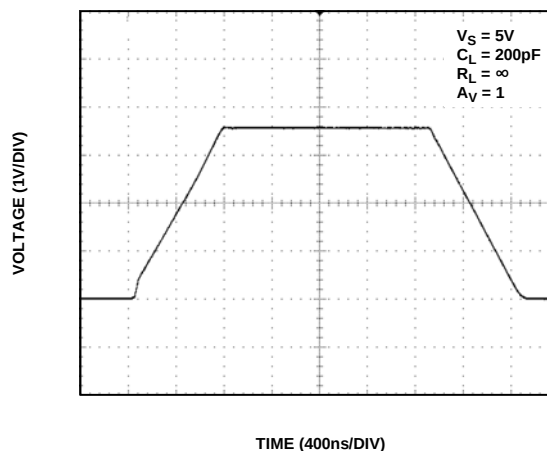


Figure 20. Large Signal Transient Response

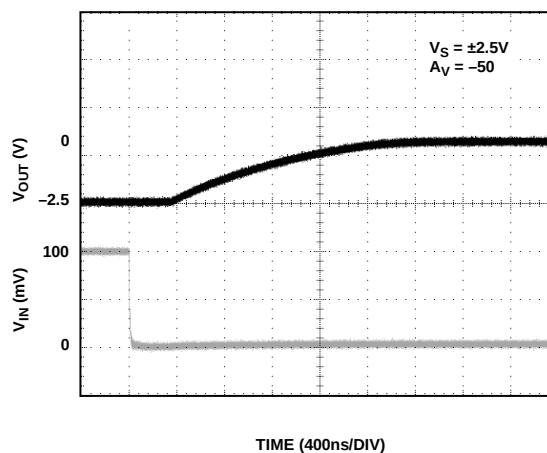


Figure 21. Positive Overload Recovery

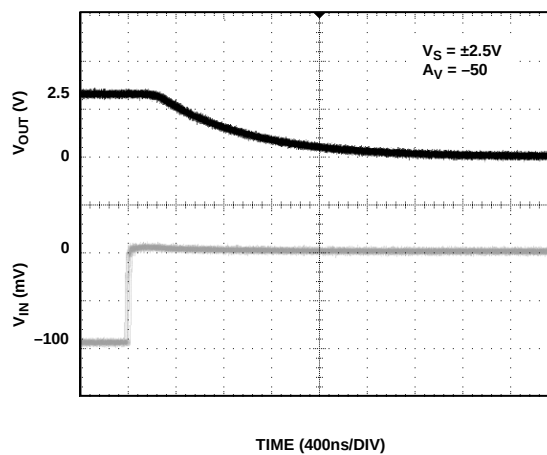
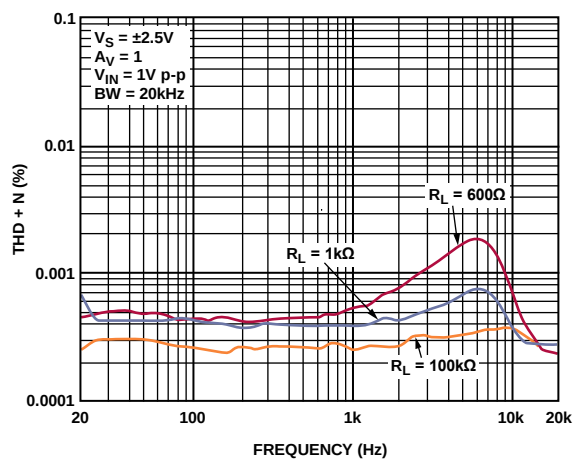
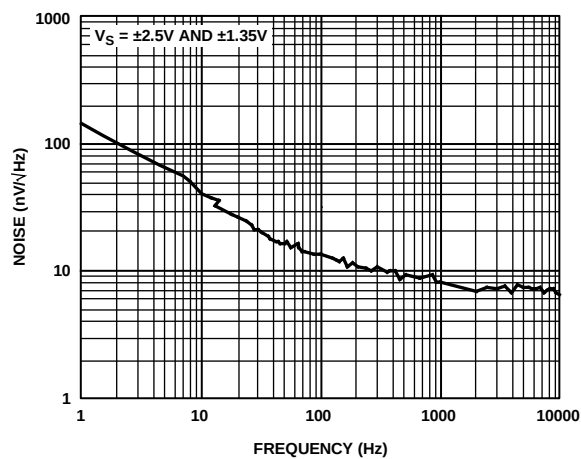


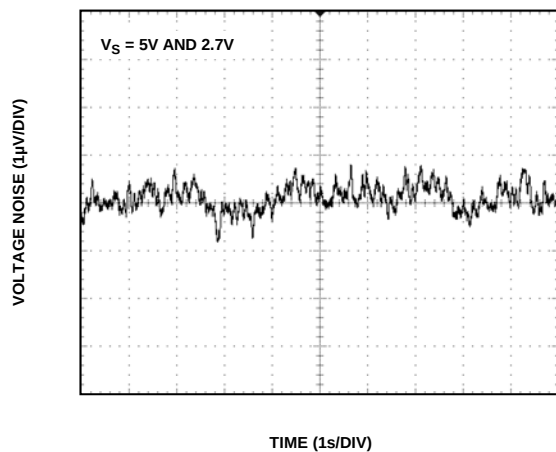
Figure 22. Negative Overload Recovery



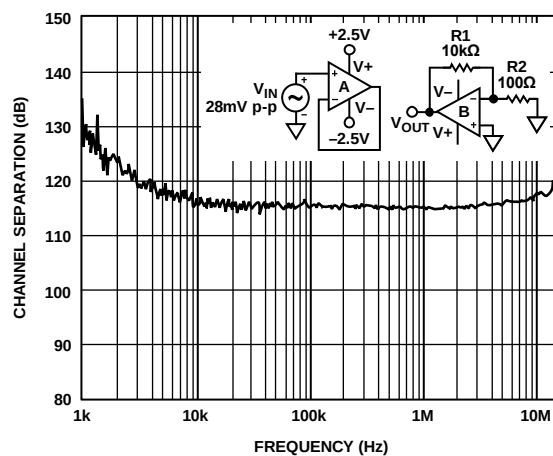
04991-021



04991-023



04991-022



04991-024

$V_S = +2.7\text{ V}$ or $\pm 1.35\text{ V}$, unless otherwise noted.

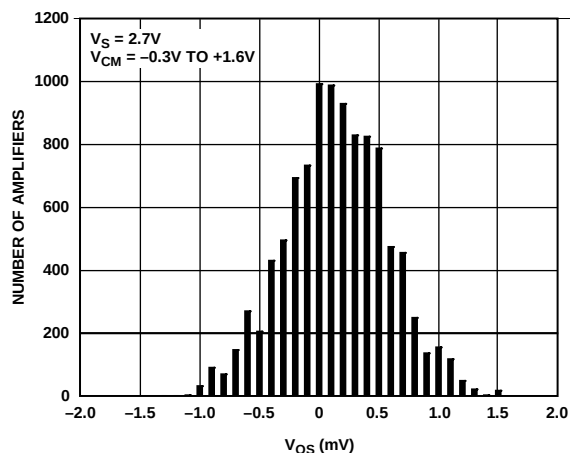


Figure 27. Input Offset Voltage Distribution

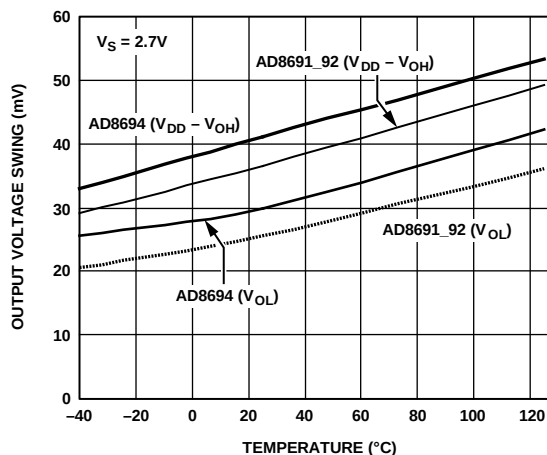


Figure 30. Output Voltage Swing vs. Temperature ($I_L = 1\text{ mA}$)

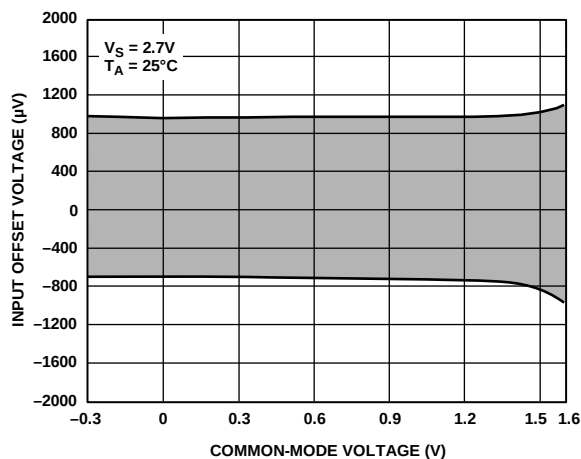


Figure 28. Input Offset Voltage vs. Common-Mode Voltage

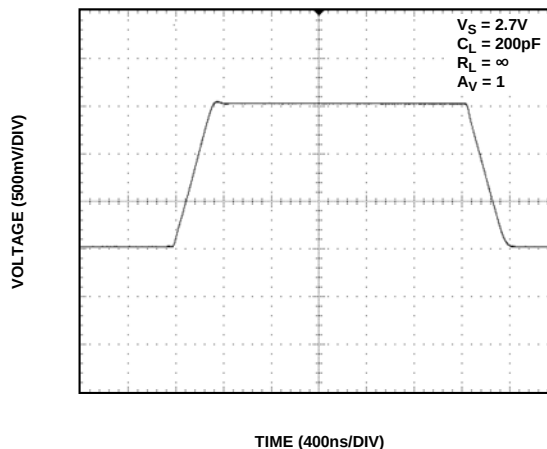


Figure 31. Large Signal Transient Response

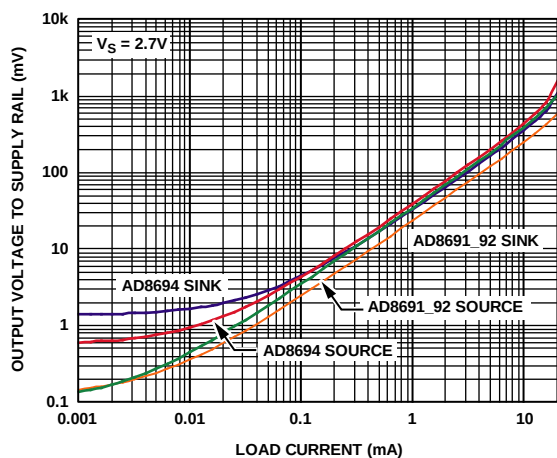
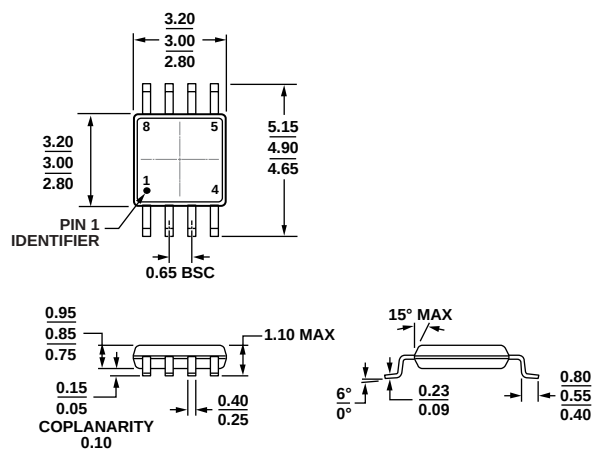


Figure 29. Output Voltage to Supply Rail vs. Load Current

OUTLINE DIMENSIONS

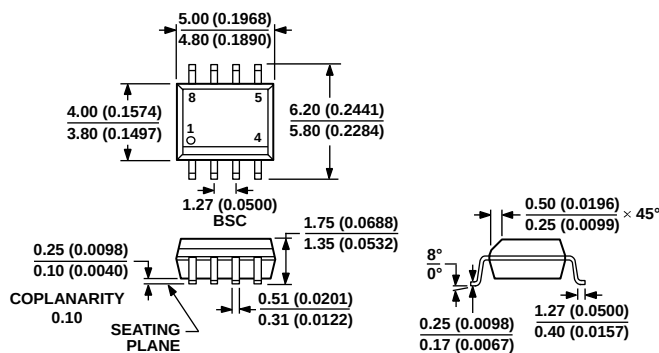


COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 32. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)

Dimensions shown in millimeters

10-07-2006-B

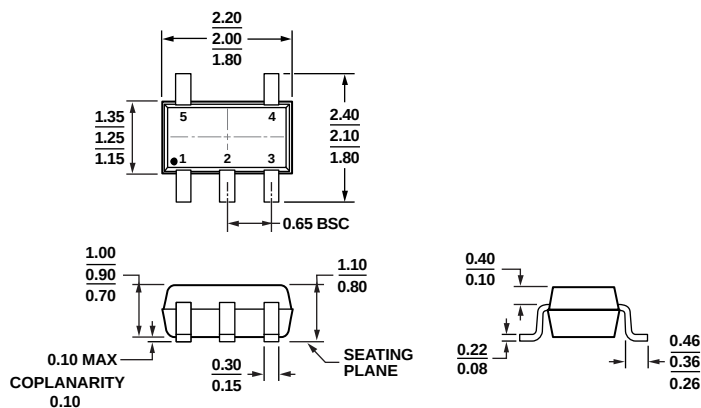


COMPLIANT TO JEDEC STANDARDS MS-012-AA

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.Figure 33. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body (R-8)

Dimensions shown in millimeters and (inches)

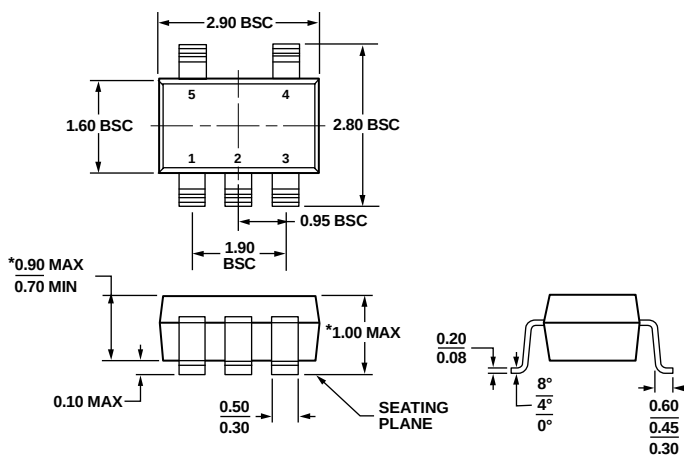
012407-A



COMPLIANT TO JEDEC STANDARDS MO-203-AA

Figure 34. 5-Lead Thin Shrink Small Outline Package [SC70]
(KS-5)

Dimensions shown in millimeters



*COMPLIANT TO JEDEC STANDARDS MO-193-AB WITH
THE EXCEPTION OF PACKAGE HEIGHT AND THICKNESS.

Figure 35. 5-Lead Thin Small Outline Transistor Package [TSOT]
(UJ-5)

Dimensions shown in millimeters

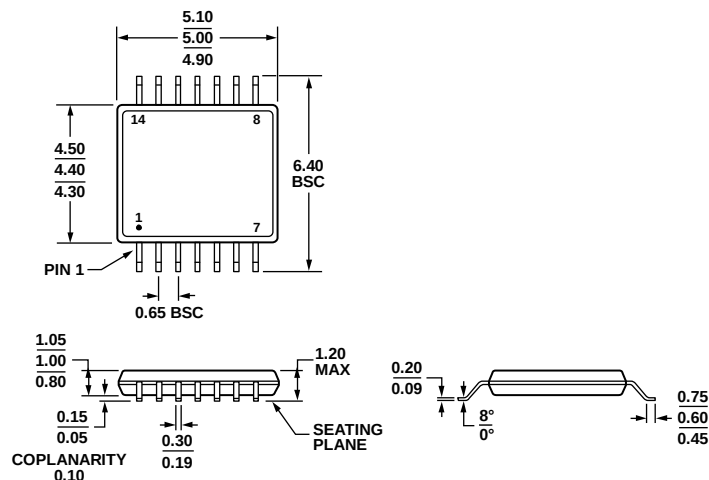
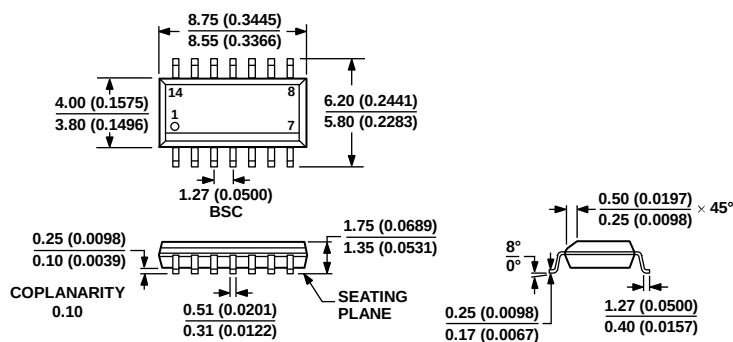


Figure 36. 14-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-14)

Dimensions shown in millimeters



CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 37. 14-Lead Standard Small Outline Package [SOIC_N]
Narrow Body (R-14)

Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model ^{1, 2}	Temperature Range	Package Description	Package Option	Branding
AD8691AUJZ-R2	−40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691AUJZ-REEL	−40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691AUJZ-REEL7	−40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691AKSZ-R2	−40°C to +125°C	5-Lead SC70	KS-5	ACA
AD8691AKSZ-REEL	−40°C to +125°C	5-Lead SC70	KS-5	ACA
AD8691AKSZ-REEL7	−40°C to +125°C	5-Lead SC70	KS-5	ACA
AD8691WAUJZ-R7	−40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691WAUJZ-RL	−40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8692ARMZ-R7	−40°C to +125°C	8-Lead MSOP	RM-8	APA
AD8692ARMZ-REEL	−40°C to +125°C	8-Lead MSOP	RM-8	APA
AD8692ARZ	−40°C to +125°C	8-Lead SOIC_N	R-8	
AD8692ARZ-REEL	−40°C to +125°C	8-Lead SOIC_N	R-8	
AD8692ARZ-REEL7	−40°C to +125°C	8-Lead SOIC_N	R-8	
AD8692WARMZ-REEL	−40°C to +125°C	8-Lead MSOP	RM-8	APA
AD8694ARUZ	−40°C to +125°C	14-Lead TSSOP	RU-14	
AD8694ARUZ-REEL	−40°C to +125°C	14-Lead TSSOP	RU-14	
AD8694WARUZ	−40°C to +125°C	14-Lead TSSOP	RU-14	
AD8694WARUZ-REEL	−40°C to +125°C	14-Lead TSSOP	RU-14	
AD8694ARZ	−40°C to +125°C	14-Lead SOIC_N	R-14	
AD8694ARZ-REEL	−40°C to +125°C	14-Lead SOIC_N	R-14	
AD8694ARZ-REEL7	−40°C to +125°C	14-Lead SOIC_N	R-14	
AD8694WAC-P3	−40°C to +125°C	Die		
AD8694WAC-P7	−40°C to +125°C	Die		

¹ Z = RoHS Compliant Part.² W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The [AD8691W](#)/[AD8692W](#)/[AD8694W](#) models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

NOTES

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Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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